Panasonic

FeRAM Embedded IC MN63Y1005 for Contactless IC card and Tag

Overview

MN63Y1005 is a nonvolatile ferroelectric random access memory (FeRAM) embedded IC for contactless IC card and tag.

The IC is powered by radio waves from a read/write unit and for incorporating nonvolatile ferroelectric RAM, the IC can retain information even when power is lost.

And it realizes high reliability with the endurance such as read/write cycles and data retention period.

Features

- FeRAM embedded
 - Nonvolatile
 - High speed read/write
 - Low power consumption
- Batteryless, wireless, contactless
 - This IC is powered by radio waves at 13.56 MHz

sent from a read/write unit, through the externally attached coil antenna to the IC.

Embedding of nonvolatile FeRAM does not require batteries.

- Note) 13.56 MHz-international standard for contactless IC cards
- Large memory configuration
 - 1024 bits of user memory area are organized into 13 areas.
- Security
 - User ID

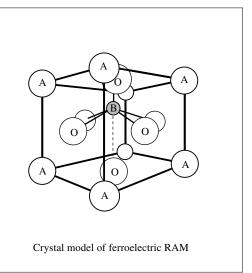
32 bits are allocated to the user ID area. The user ID can be set by a user and is unique to each card. The user ID cannot be changed once it is locked by the lock function provided.

Once locked, the lock cannot be unlocked.

• User area

User data are protected by a separate lock function provided for each of the 13 areas. Once locked, 10 of 13 locks cannot be unlocked.

- Password
 - A password is necessary for memory access.
- High reliability
 - Endurance ≥ 1 billion read/write cycles
 - Data retention ≥ 10 years 13
- Applications
- Contactless IC card / Tag



FeRAM (1 120 bit) Control Circuit Transmission Circuit

Power Circuit

Block diagram (example)

Single Chip LSI

1 The products and specifications are subject to change without any notice. Please ask for the latest product standards to guarantee the satisfaction of your product requirements.

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http://www.panasonic.co.jp/semicon/ New publication, effective from May 18, 2001

New

■ MN63Y1005 Specifications

ltem		Specifications
Nonvolatile	User area	1 024 bits FeRAM
memory	System area	96 bits FeRAM
Endurance		\geq 1 billion read/write cycles
Operating frequency		13.56 MHz
Modulation	Card to reader	847.5 kHz BPSK
	Reader to card	10 % ASK
Protocol		Matsushita proprietary protocol
Maximum read/write distance		5 cm *
Data retention period		≥ 10 years
Transfer rate		212 kbps
Bit coding		NRZ-L
Operating temperature		-10°C to 70°C
Security		ID, Password
Error checking		8 bits CRC /17 bits data
Communication method		Half duplex
Operating voltage range		3.5 V to 5.0 V
Resonant capacitor		Not included

Note) *: Depending on operating environment-power of a reader/writer, antenna size, etc.